

## QP27C256 – 256 Kilobit (32K x 8) CMOS EPROM

### General Description

The QP27C256 is a 32Kx8 (256-Kbit), UV erasable programmable read-only memory. It operates from a single +5 V supply, has a static standby mode, and features fast single address location programming. The QP27C256 meets the same specification requirements and utilizes the same programming methodology as the AMD 27C256 that it replaces. Products are available in windowed and non-windowed (OTP) ceramic hermetic packages.

Data is typically accessed in less than 55 ns, allowing high-performance microprocessors to operate without any WAIT states. The device offers separate Output Enable ( $\overline{OE}$ ) and Chip Enable ( $\overline{CE}$ ) pins, eliminating bus contention in a multiple bus system.

Typical power consumption is only 80 mW in active mode, and 100  $\mu$ W in standby mode.

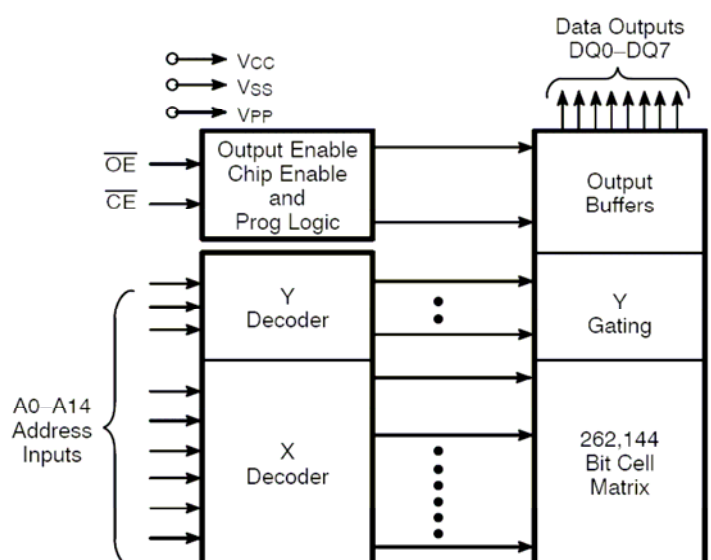
All signals are TTL levels, including programming signals. Bit locations may be programmed singly, in blocks, or at random. The device is programmed identically to the AMD27C256 device that it replaces, using the same programming algorithm (100  $\mu$ s pulses).

The QP27C256 features:

- Same programming algorithm as the AMD27C256, allowing it to be programmed using the same equipment, data and algorithm. When programming this device select AMD as the manufacturer and 27C256 as the device type.
- Speed options as fast as 55ns
- JEDEC Pinout
- Single +5V power supply
- CMOS and TTL input/output compatibility
- Two line control functions
- Programming time typically 4 seconds.

The device/family is constructed using an advanced UV CMOS wafer fabrication process.

### Block Diagram

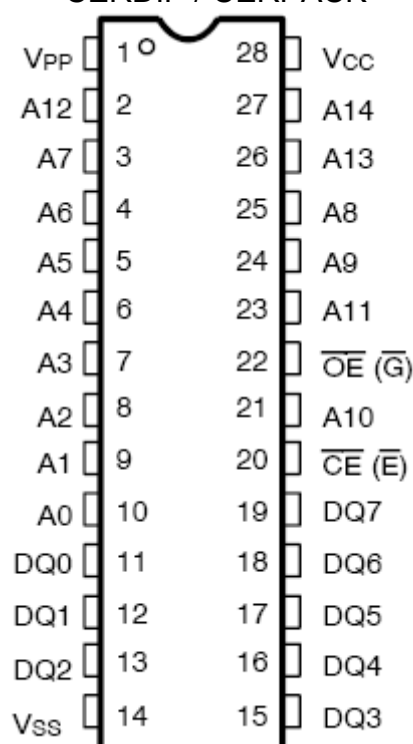


| Pin Name                        | Function                |
|---------------------------------|-------------------------|
| $A_0 - A_{14}$                  | Address Inputs          |
| $\overline{CE} (\overline{E})$  | Chip Enable Input       |
| $D_{Q0} - D_{Q7}$               | Data Input/Output       |
| $\overline{OE} (\overline{G})$  | Output Enable Input     |
| $\overline{PGM} (\overline{P})$ | Program Enable Input    |
| $V_{CC}$                        | $V_{CC}$ Supply Voltage |
| $V_{PP}$                        | Program Voltage Input   |
| $V_{SS}$                        | Ground                  |
| NC                              | No Connection           |

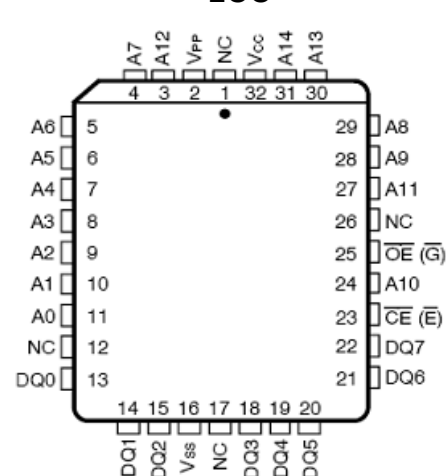
## Connection Diagrams

Device Type

CERDIP / CERPAC



LCC



## Functional Description

### Device Erasure

In order to clear all locations of their programmed contents, the device must be exposed to an ultraviolet light source. A dosage of 15 W seconds/cm<sup>2</sup> is required to completely erase the device. This dosage can be obtained by exposure to an ultraviolet lamp with a wavelength of 2537Å and an intensity of 12,000 μW/cm<sup>2</sup> for 15 to 20 minutes. The device should be directly under and about one inch from the source, and all filters should be removed from the UV light source prior to erasure.

Note that all UV erasable devices will erase with light sources having wavelengths shorter than 4000Å, such as fluorescent light and sunlight. Although the erasure process happens over a much longer time period, exposure to any light source should be prevented for maximum system reliability. Simply cover the package window with an opaque label or substance.

### Device Programming

Upon delivery, or after each erasure, the device has all of its bits in the “ONE”, or HIGH state. “ZEROS” are loaded into the device through the programming procedure.

The device enters the programming mode when  $12.75\text{V} \pm 0.25\text{V}$  is applied to the  $V_{PP}$  pin, and both  $\overline{OE}$  is at  $V_{IH}$  &  $\overline{CE}$  are at  $V_{IL}$ .

For programming, the data to be programmed is applied 8 bits in parallel to the data pins.

The programming algorithm uses a  $100\text{ }\mu\text{s}$  programming pulse and gives each address only as many pulses as needed to reliably program the data. After each pulse is applied to a given address, the data in that address is verified. If the data does not verify, additional pulses are given until it verifies or the maximum pulses allowed is reached. This process is repeated while sequencing through each address of the device. This part of the algorithm is done with  $V_{CC} = 6.25\text{ V}$  to assure that each bit is programmed to a sufficiently high threshold voltage. After the final address is completed, the entire EPROM memory is verified at  $V_{CC} = V_{PP} = 5.25\text{ V}$ .

### **Program Inhibit**

Programming different data to multiple devices in parallel is easily accomplished. Except for  $\overline{CE}$ , all like inputs of the devices may be common. A TTL low-level program pulse applied to one device's  $\overline{CE}$  input with  $V_{PP} = 12.75\text{ V} \pm 0.25\text{ V}$  and  $\overline{OE}$  HIGH will program that particular device. A high-level  $\overline{CE}$  input inhibits the other devices from being programmed.

### **Program Verify**

Verification should be performed on the programmed bits to determine that they were correctly programmed. Verify should be performed with  $\overline{OE}$  at  $V_{IL}$ ,  $\overline{CE}$  at  $V_{IH}$  and  $V_{PP}$  between  $12.5\text{ V}$  and  $13.0\text{ V}$ .

### **Autoselect Mode**

The autoselect mode provides manufacturer and device identification through identifier codes on DQ0–DQ7. This mode is primarily intended for programming equipment to automatically match a device to be programmed with its corresponding programming algorithm. This mode is functional in the  $25^{\circ}\text{C} \pm 5^{\circ}\text{C}$  ambient temperature range that is required when programming the device. To activate this mode, the programming equipment must force  $V_H$  on address line A9. Two identifier bytes may then be sequenced from the device outputs by toggling address line A0 from  $V_{IL}$  to  $V_{IH}$  (that is, changing the address from 00h to 01h). All other address lines must be held at  $V_{IL}$  during the autoselect mode. Byte 0 ( $A0 = V_{IL}$ ) represents the manufacturer code, and Byte 1 ( $A0 = V_{IH}$ ), the device identifier code. Both codes have odd parity, with DQ7 as the parity bit.

### **Read Mode**

To obtain data at the device outputs, Chip Enable ( $\overline{CE}$ ) and Output Enable ( $\overline{OE}$ ) must be driven low.  $\overline{CE}$  controls the power to the device and is typically used to select the device.  $\overline{OE}$  enables the device to output data, independent of device selection. Addresses must be stable for at least  $t_{ACC}-t_{OE}$ .

### **Standby Mode**

The device enters the CMOS standby mode when  $\overline{CE}$  is at  $V_{CC} \pm 0.3\text{ V}$ . Maximum  $V_{CC}$  current is reduced to  $100\text{ }\mu\text{A}$ .

The device enters the TTL-standby mode when  $\overline{CE}$  is at  $V_{IH}$ . Maximum  $V_{CC}$  current is reduced to  $1.0\text{ mA}$ . When in either standby mode, the device places its outputs in a high-impedance state, independent of the  $\overline{OE}$  input.

### **Output OR Connection**

To accommodate multiple memory connections, a two-line control function provides:

- Low memory power dissipation
- Assurance that output bus contention will not occur.

$\overline{CE}$  should be decoded and used as the primary device selecting function, while  $\overline{OE}$  be made a common connection to all devices in the array and connected to the READ line from the system control bus. This assures that all deselected memory devices are in their low-power standby mode and that the output pins are only active when data is desired from a particular memory device.

### **System Applications**

During the switch between active and standby conditions, transient current peaks are produced on the rising and falling edges of Chip Enable. The magnitude of these transient current peaks is dependent on the output capacitance loading of the device. As a minimum, a  $0.1\text{ }\mu\text{F}$  ceramic capacitor (high frequency, low inductance) should be used on each device between  $V_{CC}$  and  $V_{SS}$  to minimize transient effects. In addition, to overcome the voltage drop caused by the inductive effects of the printed circuit board traces on EPROM arrays, a  $4.7\text{ }\mu\text{F}$  bulk electrolytic capacitor should be used

between  $V_{CC}$  and  $V_{SS}$  for each eight devices. The location of the capacitor should be close to where the power supply is connected to the array.

**MODE Select Table**

| Mode              | $\overline{CE}$   | $\overline{OE}$ | $A_0$    | $A_9$ | $V_{PP}$ | Outputs   | Notes       |
|-------------------|-------------------|-----------------|----------|-------|----------|-----------|-------------|
| Read              | $V_{IL}$          | $V_{IL}$        | X        | X     | X        | $D_{OUT}$ | \1          |
| Output Disable    | X                 | $V_{IH}$        | X        | X     | X        | High Z    | \1          |
| Standby (TTL)     | $V_{IH}$          | X               | X        | X     | X        | High Z    | \1          |
| Standby (CMOS)    | $V_{CC} \pm 0.3V$ | X               | X        | X     | X        | High Z    | \1          |
| Program           | $V_{IL}$          | $V_{IH}$        | X        | X     | $V_{PP}$ | $D_{IN}$  | \1          |
| Program Verify    | $V_{IH}$          | $V_{IL}$        | X        | X     | $V_{PP}$ | $D_{OUT}$ | \1          |
| Program Inhibit   | $V_{IH}$          | $V_{IH}$        | X        | X     | $V_{PP}$ | High Z    | \1          |
| Manufacturer Code | $V_{IL}$          | $V_{IL}$        | $V_{IL}$ | $V_H$ | X        | 01h       | \1 \2 \3 \4 |
| Device Code       | $V_{IL}$          | $V_{IL}$        | $V_{IH}$ | $V_H$ | X        | 10h       | \1 \2 \3 \4 |

Notes:

\1 X = Either  $V_{IH}$  or  $V_{IL}$

\2  $V_H = 12.0V \pm 0.5V$

\3  $A_1-A_8$  &  $A_{10}-A_{14} = V_{IL}$

\4 Device Manufacture Code and Device ID match original AMD device for programming compatibility

### Absolute Maximum Ratings

Stresses above the AMR may cause permanent damage, extended operation at AMR may degrade performance and affect reliability

| Condition                                                                                       | Units                      | Notes |
|-------------------------------------------------------------------------------------------------|----------------------------|-------|
| Power Supply ( $V_{CC}$ )                                                                       | -0.6 to +7.0 Volts DC      |       |
| Voltage with Respect to $V_{SS}$                                                                |                            |       |
| All pins except $A_9$ , $V_{PP}$ , $V_{CC}$                                                     | -0.6 to $V_{CC}+0.6$ Volts | \5 \9 |
| $A_9$ and $V_{PP}$                                                                              | -0.6 to 13.5 Volts         | \6 \9 |
| Storage Temperature Range                                                                       | -65 to +150 °C             | \7    |
| Lead Temperature (soldering, 10 seconds)                                                        | +300 °C                    |       |
| Junction Temperature ( $T_J$ )                                                                  | +150 °C                    | \7    |
| Maximum Operating Temperature                                                                   |                            |       |
| Commercial Devices                                                                              | 0 to 70 °C                 | \7 \8 |
| Industrial Devices                                                                              | -40 to 85 °C               | \7 \8 |
| Military Temperature Range                                                                      | -55 to 125 °C              | \7 \8 |
| Data Retention                                                                                  | 10 Years, minimum          |       |
| Device must not be removed from or inserted into a socket when $V_{CC}$ or $V_{PP}$ is applied. |                            |       |

### Recommended Operating Conditions

| Condition                                     | Units                    | Notes |
|-----------------------------------------------|--------------------------|-------|
| Supply Voltage Range ( $V_{CC}$ )             | 4.5 to 5.5 Volts DC      |       |
| Input or Output Voltage Range                 | 0.0 to $V_{CC}$ Volts DC | \5 \6 |
| Minimum High-Level Input Voltage ( $V_{IH}$ ) | 2.0 Volts DC             |       |
| Maximum Low-Level Input Voltage ( $V_{IL}$ )  | 0.8 Volts DC             |       |
| Case Operating Range ( $T_c$ )                |                          |       |
| Commercial Devices                            | 0 to 70 °C               | \7 \8 |
| Industrial Devices                            | -40 to 85 °C             | \7 \8 |
| Military Temperature Range                    | -55 to 125 °C            | \7 \8 |

- \5 – Minimum DC Input Voltage on input or I/O pins  $-0.5V$ . During voltage transitions, the input may overshoot  $V_{SS}$  to  $-2.0V$  for periods of up to 20ns. Maximum DC voltage on input and I/O pins is  $V_{CC}+0.5V$ . During transitions, input and I/O pins may overshoot to  $V_{CC} +2.0V$  for periods up to 20ns.
- \6 – Minimum DC Input Voltage on  $A_9$  is  $-0.5V$ . During voltage transitions,  $A_9$  and  $V_{PP}$  may overshoot  $V_{SS}$  to  $-2.0V$  for periods of up to 20ns.  $A_9$  and  $V_{PP}$  must not exceed  $+13.5V$  at any time.
- \7 – Do not exceed  $125^{\circ}C$   $T_C$  or  $T_J$  for plastic package devices.
- \8 – Maximum PD, Maximum  $T_J$  Are Not to Be Exceeded.
- \9 – During transitions, the inputs may undershoot to  $-2.0V$  dc for periods less than 20 ns.
- \10 –  $V_{PP}$  may be connected directly to  $V_{CC}$  except during programming.
- \11 – Qualification Only.
- \12 – If not tested, shall be guaranteed to the limits specified.

**TABLE I – ELECTRICAL PERFORMANCE CHARACTERISTICS**

| Test                   | Symbol        | Conditions<br>$-55^{\circ}C \leq T_A \leq +125^{\circ}C$<br>Unless Otherwise Specified | Min   | Max   | Unit    |
|------------------------|---------------|----------------------------------------------------------------------------------------|-------|-------|---------|
| Input Load Current     | $I_{LI}$      | $V_{IN} = 5.5V$ or $0.0V$<br>All other inputs at either $V_{CC}$ or GND                | -10.0 | +10.0 | $\mu A$ |
| Output Leakage Current | $I_{LO}$      | $V_{OIT} = 5.5V$ or $0.0V$                                                             | -10.0 | +10.0 | $\mu A$ |
| Operating Current, TTL | $I_{CC\ TTL}$ | $\overline{OE} = \overline{CE} = V_{IL}$ 35ns                                          |       | 85    | mA      |
|                        |               | $V_{PP} = V_{CC}$ 45ns                                                                 |       | 60    | mA      |
|                        |               | $O_0-O_7 = 0$ mA 55ns                                                                  |       | 60    | mA      |
|                        |               | $f = 1/t_{ACCmax}$ 70ns                                                                |       | 60    | mA      |
|                        |               | QP27C256 90ns                                                                          |       | 60    | mA      |
|                        |               | QP27C256L 90ns                                                                         |       | 50    | mA      |
|                        |               | QP27C256 120ns                                                                         |       | 60    | mA      |
|                        |               | QP27C256L 120ns                                                                        |       | 50    | mA      |
|                        |               | QP27C256 150ns                                                                         |       | 60    | mA      |
|                        |               | QP27C256L 150ns                                                                        |       | 50    | mA      |
|                        |               | QP27C256 170ns                                                                         |       | 60    | mA      |
|                        |               | QP27C256L 170ns                                                                        |       | 50    | mA      |
|                        |               | QP27C256 200ns                                                                         |       | 60    | mA      |
|                        |               | QP27C256L 200ns                                                                        |       | 50    | mA      |
|                        |               | QP27C256 250ns                                                                         |       | 60    | mA      |
|                        |               | QP27C256L 250ns                                                                        |       | 50    | mA      |
|                        |               | QP27C256 300ns                                                                         |       | 60    | mA      |
|                        |               | QP27C256L 300ns                                                                        |       | 50    | mA      |

**TABLE I – ELECTRICAL PERFORMANCE CHARACTERISTICS**

| Test                    | Symbol               | Conditions<br>-55°C ≤ TA ≤ +125°C<br>Unless Otherwise Specified | Min | Max | Unit |
|-------------------------|----------------------|-----------------------------------------------------------------|-----|-----|------|
| Operating Current, CMOS | I <sub>CC CMOS</sub> | $\overline{OE} = \overline{CE} = V_{IL}$ 35ns                   |     | 60  | mA   |
|                         |                      | V <sub>PP</sub> = V <sub>CC</sub> 45ns                          |     | 60  | mA   |
|                         |                      | O <sub>0</sub> -O <sub>7</sub> = 0 mA 55ns                      |     | 60  | mA   |
|                         |                      | f = 1/t <sub>ACCmax</sub> 70ns                                  |     | 60  | mA   |
|                         |                      | QP27C256 90ns                                                   |     | 60  | mA   |
|                         |                      | QP27C256L 90ns                                                  |     | 25  | mA   |
|                         |                      | QP27C256 120ns                                                  |     | 60  | mA   |
|                         |                      | QP27C256L 120ns                                                 |     | 25  | mA   |
|                         |                      | QP27C256 150ns                                                  |     | 60  | mA   |
|                         |                      | QP27C256L 150ns                                                 |     | 25  | mA   |
|                         |                      | QP27C256 170ns                                                  |     | 60  | mA   |
|                         |                      | QP27C256L 170ns                                                 |     | 25  | mA   |
|                         |                      | QP27C256 200ns                                                  |     | 60  | mA   |
|                         |                      | QP27C256L 200ns                                                 |     | 25  | mA   |
|                         |                      | QP27C256 250ns                                                  |     | 60  | mA   |
|                         |                      | QP27C256L 250ns                                                 |     | 25  | mA   |
|                         |                      | QP27C256 300ns                                                  |     | 60  | mA   |
|                         |                      | QP27C256L 300ns                                                 |     | 25  | mA   |

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| Test                 | Symbol              | Conditions<br>-55°C ≤ TA ≤ +125°C<br>Unless Otherwise Specified | Min | Max | Unit |
|----------------------|---------------------|-----------------------------------------------------------------|-----|-----|------|
| Standby Current, TTL | I <sub>SB TTL</sub> | $\overline{CE} = V_{IH}$ 35ns                                   |     | 25  | mA   |
|                      |                     | V <sub>CC</sub> = 5.5V 45ns                                     |     | 25  | mA   |
|                      |                     | f = 0 MHz 55ns                                                  |     | 25  | mA   |
|                      |                     | O <sub>0</sub> -O <sub>7</sub> = 0 mA 70ns                      |     | 25  | mA   |
|                      |                     | QP27C256 90ns                                                   |     | 25  | mA   |
|                      |                     | QP27C256L 90ns                                                  |     | 5   | mA   |
|                      |                     | QP27C256 120ns                                                  |     | 25  | mA   |
|                      |                     | QP27C256L 120ns                                                 |     | 5   | mA   |
|                      |                     | QP27C256 150ns                                                  |     | 25  | mA   |
|                      |                     | QP27C256L 150ns                                                 |     | 3   | mA   |
|                      |                     | QP27C256 170ns                                                  |     | 25  | mA   |
|                      |                     | QP27C256L 170ns                                                 |     | 3   | mA   |
|                      |                     | QP27C256 200ns                                                  |     | 25  | mA   |
|                      |                     | QP27C256L 200ns                                                 |     | 3   | mA   |
|                      |                     | QP27C256 250ns                                                  |     | 25  | mA   |
|                      |                     | QP27C256L 250ns                                                 |     | 3   | mA   |
|                      |                     | QP27C256 300ns                                                  |     | 25  | mA   |
|                      |                     | QP27C256L 300ns                                                 |     | 3   | mA   |

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| Test                                     | Symbol               | Conditions<br>-55°C ≤ TA ≤ +125°C<br>Unless Otherwise Specified                                    | Min                   | Max                  | Unit |
|------------------------------------------|----------------------|----------------------------------------------------------------------------------------------------|-----------------------|----------------------|------|
| Standby Current, CMOS                    | I <sub>SB</sub> CMOS | $\overline{CE} = V_{IH}$ 35ns                                                                      |                       | 25                   | mA   |
|                                          |                      | V <sub>CC</sub> = 5.5V 45ns                                                                        |                       | 25                   | mA   |
|                                          |                      | f = 0 MHz 55ns                                                                                     |                       | 25                   | mA   |
|                                          |                      | O <sub>0</sub> -O <sub>7</sub> = 0 mA 70ns                                                         |                       | 25                   | mA   |
|                                          |                      | QP27C256 90ns                                                                                      |                       | 25                   | mA   |
|                                          |                      | QP27C256L 90ns                                                                                     |                       | 300                  | uA   |
|                                          |                      | QP27C256 120ns                                                                                     |                       | 25                   | mA   |
|                                          |                      | QP27C256L 120ns                                                                                    |                       | 300                  | uA   |
|                                          |                      | QP27C256 150ns                                                                                     |                       | 25                   | mA   |
|                                          |                      | QP27C256L 150ns                                                                                    |                       | 300                  | uA   |
|                                          |                      | QP27C256 170ns                                                                                     |                       | 25                   | mA   |
|                                          |                      | QP27C256L 170ns                                                                                    |                       | 300                  | uA   |
|                                          |                      | QP27C256 200ns                                                                                     |                       | 25                   | mA   |
|                                          |                      | QP27C256L 200ns                                                                                    |                       | 300                  | uA   |
|                                          |                      | QP27C256 250ns                                                                                     |                       | 25                   | mA   |
|                                          |                      | QP27C256L 250ns                                                                                    |                       | 300                  | uA   |
|                                          |                      | QP27C256 300ns                                                                                     |                       | 25                   | mA   |
|                                          |                      | QP27C256L 300ns                                                                                    |                       | 300                  | uA   |
| V <sub>PP</sub> Read Current             | I <sub>PP</sub>      | V <sub>PP</sub> = V <sub>CC</sub> = 5.5V                                                           |                       | 10                   | μA   |
| Input Low Voltage TTL                    | V <sub>IL</sub>      | V <sub>PP</sub> = V <sub>CC</sub>                                                                  | -0.1                  | 0.8                  | V    |
| Input Low Voltage CMOS                   | V <sub>IL</sub>      | V <sub>PP</sub> = V <sub>CC</sub>                                                                  | -0.2                  | 0.2                  | V    |
| Input High Voltage TTL                   | V <sub>IH</sub>      | V <sub>PP</sub> = V <sub>CC</sub>                                                                  | 2.0                   | V <sub>CC</sub> +1.0 | V    |
| Input High Voltage CMOS                  | V <sub>IH</sub>      | V <sub>PP</sub> = V <sub>CC</sub>                                                                  | V <sub>CC</sub> -0.2  | V <sub>CC</sub> +0.2 | V    |
| Output Low Voltage                       | V <sub>OL</sub>      | I <sub>OL</sub> = 2.1mA                                                                            |                       | 0.45                 | V    |
| Output High Voltage                      | V <sub>OH</sub>      | V <sub>IL</sub> = 0.8V, V <sub>IH</sub> = 2.0V<br>I <sub>OL</sub> = -400μA, V <sub>CC</sub> = 4.5V | 2.4                   |                      | V    |
| Output Short Circuit Current             | I <sub>OS</sub>      | V <sub>OUT</sub> = 0.0V<br>Duration not to exceed 1 second,<br>one output at a time                |                       | -100                 | mA   |
| V <sub>PP</sub> Read Voltage $\sqrt{10}$ | V <sub>PP</sub>      |                                                                                                    | V <sub>CC</sub> - 0.7 | V <sub>CC</sub>      | V    |

**TABLE I – ELECTRICAL PERFORMANCE CHARACTERISTICS**

| Test                            | Symbol           | Conditions<br>-55°C ≤ TA ≤ +125°C<br>Unless Otherwise Specified | Min | Max | Unit |
|---------------------------------|------------------|-----------------------------------------------------------------|-----|-----|------|
| Address to Output Delay         | t <sub>ACC</sub> | $\overline{CE} = V_{IL}$ 35ns                                   |     | 35  | ns   |
|                                 |                  | $\overline{OE} = V_{IL}$ 45ns                                   |     | 45  | ns   |
|                                 |                  | 55ns                                                            |     | 55  | ns   |
|                                 |                  | 70ns                                                            |     | 70  | ns   |
|                                 |                  | 90ns                                                            |     | 90  | ns   |
|                                 |                  | 120ns                                                           |     | 120 | ns   |
|                                 |                  | 150ns                                                           |     | 150 | ns   |
|                                 |                  | 170ns                                                           |     | 170 | ns   |
|                                 |                  | 200ns                                                           |     | 200 | ns   |
|                                 |                  | 250ns                                                           |     | 250 | ns   |
|                                 |                  | 300ns                                                           |     | 300 | ns   |
| $\overline{CE}$ to Output Delay | t <sub>CE</sub>  | $\overline{OE} = V_{IL}$ 35ns                                   |     | 40  | ns   |
|                                 |                  | 45ns                                                            |     | 45  | ns   |
|                                 |                  | 55ns                                                            |     | 55  | ns   |
|                                 |                  | 70ns                                                            |     | 70  | ns   |
|                                 |                  | 90ns                                                            |     | 90  | ns   |
|                                 |                  | 120ns                                                           |     | 120 | ns   |
|                                 |                  | 150ns                                                           |     | 150 | ns   |
|                                 |                  | 170ns                                                           |     | 170 | ns   |
|                                 |                  | 200ns                                                           |     | 200 | ns   |
|                                 |                  | 250ns                                                           |     | 250 | ns   |
|                                 |                  | 300ns                                                           |     | 300 | ns   |

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| Test                                                                                                         | Symbol    | Conditions<br>-55°C ≤ TA ≤ +125°C<br>Unless Otherwise Specified | Min | Max | Unit |
|--------------------------------------------------------------------------------------------------------------|-----------|-----------------------------------------------------------------|-----|-----|------|
| $\overline{OE}$ to Output Delay                                                                              | $t_{OE}$  | $\overline{CE} = V_{IL}$ 35ns                                   |     | 20  | ns   |
|                                                                                                              |           | 45ns                                                            |     | 15  | ns   |
|                                                                                                              |           | 55ns                                                            |     | 25  | ns   |
|                                                                                                              |           | 70ns                                                            |     | 25  | ns   |
|                                                                                                              |           | 90ns                                                            |     | 30  | ns   |
|                                                                                                              |           | 120ns                                                           |     | 35  | ns   |
|                                                                                                              |           | 150ns                                                           |     | 40  | ns   |
|                                                                                                              |           | 170ns                                                           |     | 40  | ns   |
|                                                                                                              |           | 200ns                                                           |     | 60  | ns   |
|                                                                                                              |           | 250ns                                                           |     | 60  | ns   |
|                                                                                                              |           | 300ns                                                           |     | 60  | ns   |
| $\overline{OE}$ high to Output Float                                                                         | $t_{DF}$  | $\overline{OE} = V_{IL}$ 35ns                                   |     | 15  | ns   |
|                                                                                                              |           | 45ns                                                            |     | 15  | ns   |
|                                                                                                              |           | 55ns                                                            |     | 20  | ns   |
|                                                                                                              |           | 70ns                                                            |     | 25  | ns   |
|                                                                                                              |           | 90ns                                                            |     | 30  | ns   |
|                                                                                                              |           | 120ns                                                           |     | 35  | ns   |
|                                                                                                              |           | 150ns                                                           |     | 40  | ns   |
|                                                                                                              |           | 170ns                                                           |     | 40  | ns   |
|                                                                                                              |           | 200ns                                                           |     | 55  | ns   |
|                                                                                                              |           | 250ns                                                           |     | 60  | ns   |
|                                                                                                              |           | 300ns                                                           |     | 60  | ns   |
| Output hold from<br>Addresses, $\overline{OE}$ or $\overline{CE}$<br>Whichever Occurred First $\frac{1}{12}$ | $t_{OH}$  | $\overline{CE} = \overline{OE} = V_{IL}$                        | 0   |     | ns   |
| Input Capacitance                                                                                            | $C_{IN}$  | $V_{IN}=0V, f=1Mhz$                                             |     | 12  | pF   |
| Output Capacitance                                                                                           | $C_{OUT}$ | $V_{IN}=0V, f=1Mhz$                                             |     | 14  | pF   |

## Ordering Information

| Part Number    | Package (Mil-Std-1835)    | Generic          |
|----------------|---------------------------|------------------|
| 5962-8606301UA | GDIP3-T28 CDIP4-T28 (DIP) | QP27C256L-200/UA |
| 5962-8606301XA | GDIP1-T28 CDIP2-T28 (DIP) | QP27C256L-200/XA |
| 5962-8606301YA | CQCC1-N32 (LCC)           | QP27C256L-200/YA |
| 5962-8606301YC | CQCC1-N32 (LCC)           | QP27C256L-200/YC |
| 5962-8606301ZA | JLCC-N32                  | QP27C256L-200/ZA |
| 5962-8606302UA | GDIP3-T28 CDIP4-T28 (DIP) | QP27C256L-250/UA |
| 5962-8606302XA | GDIP1-T28 CDIP2-T28 (DIP) | QP27C256L-250/XA |
| 5962-8606302YA | CQCC1-N32 (LCC)           | QP27C256L-250/YA |
| 5962-8606302YC | CQCC1-N32 (LCC)           | QP27C256L-250/YC |
| 5962-8606302ZA | JLCC-N32                  | QP27C256L-250/ZA |
| 5962-8606303UA | GDIP3-T28 CDIP4-T28 (DIP) | QP27C256L-300/UA |
| 5962-8606303XA | GDIP1-T28 CDIP2-T28 (DIP) | QP27C256L-300/XA |
| 5962-8606303YA | CQCC1-N32 (LCC)           | QP27C256L-300/YA |
| 5962-8606303YC | CQCC1-N32 (LCC)           | QP27C256L-300/YC |
| 5962-8606303ZA | JLCC-N32                  | QP27C256L-300/ZA |
| 5962-8606304UA | GDIP3-T28 CDIP4-T28 (DIP) | QP27C256L-170/UA |
| 5962-8606304XA | GDIP1-T28 CDIP2-T28 (DIP) | QP27C256L-170/XA |
| 5962-8606304YA | CQCC1-N32 (LCC)           | QP27C256L-170/YA |
| 5962-8606304YC | CQCC1-N32 (LCC)           | QP27C256L-170/YC |
| 5962-8606304ZA | JLCC-N32                  | QP27C256L-170/ZA |
| 5962-8606305UA | GDIP3-T28 CDIP4-T28 (DIP) | QP27C256L-150/UA |
| 5962-8606305XA | GDIP1-T28 CDIP2-T28 (DIP) | QP27C256L-150/XA |
| 5962-8606305YA | CQCC1-N32 (LCC)           | QP27C256L-150/YA |
| 5962-8606305YC | CQCC1-N32 (LCC)           | QP27C256L-150/YC |
| 5962-8606305ZA | JLCC-N32                  | QP27C256L-150/ZA |
| 5962-8606306UA | GDIP3-T28 CDIP4-T28 (DIP) | QP27C256L-120/UA |
| 5962-8606306XA | GDIP1-T28 CDIP2-T28 (DIP) | QP27C256L-120/XA |
| 5962-8606306YA | CQCC1-N32 (LCC)           | QP27C256L-120/YA |
| 5962-8606306YC | CQCC1-N32 (LCC)           | QP27C256L-120/YC |
| 5962-8606306ZA | JLCC-N32                  | QP27C256L-120/ZA |
| 5962-8606307UA | GDIP3-T28 CDIP4-T28 (DIP) | QP27C256L-90/UA  |
| 5962-8606307XA | GDIP1-T28 CDIP2-T28 (DIP) | QP27C256L-90/XA  |
| 5962-8606307YA | CQCC1-N32 (LCC)           | QP27C256L-90/YA  |
| 5962-8606307YC | CQCC1-N32 (LCC)           | QP27C256L-90/YC  |
| 5962-8606307ZA | JLCC-N32                  | QP27C256L-90/ZA  |
| 5962-8606308UA | GDIP3-T28 CDIP4-T28 (DIP) | QP27C256-70/UA   |
| 5962-8606308XA | GDIP1-T28 CDIP2-T28 (DIP) | QP27C256-70/XA   |
| 5962-8606308YA | CQCC1-N32 (LCC)           | QP27C256-70/YA   |
| 5962-8606308YC | CQCC1-N32 (LCC)           | QP27C256-70/YC   |
| 5962-8606308ZA | JLCC-N32                  | QP27C256-70/ZA   |
| 5962-8606309UA | GDIP3-T28 CDIP4-T28 (DIP) | QP27C256-55/UA   |
| 5962-8606309XA | GDIP1-T28 CDIP2-T28 (DIP) | QP27C256-55/XA   |
| 5962-8606309YA | CQCC1-N32 (LCC)           | QP27C256-55/YA   |
| 5962-8606309YC | CQCC1-N32 (LCC)           | QP27C256-55/YC   |
| 5962-8606310UA | GDIP3-T28 CDIP4-T28 (DIP) | QP27C256-45/UA   |
| 5962-8606310XA | GDIP1-T28 CDIP2-T28 (DIP) | QP27C256-45/XA   |
| 5962-8606310YA | CQCC1-N32 (LCC)           | QP27C256-45/YA   |
| 5962-8606310YC | CQCC1-N32 (LCC)           | QP27C256-45/YC   |

| Part Number     | Package (Mil-Std-1835)    | Generic         |
|-----------------|---------------------------|-----------------|
| 5962-8606311QXA | GDIP1-T28 CDIP2-T28 (DIP) | QP27C256-200/XA |
| 5962-8606311QYA | CQCC1-N32 (LCC)           | QP27C256-200/YA |
| 5962-8606311UA  | GDIP3-T28 CDIP4-T28 (DIP) | QP27C256-200/UA |
| 5962-8606311XA  | GDIP1-T28 CDIP2-T28 (DIP) | QP27C256-200/XA |
| 5962-8606311YA  | CQCC1-N32 (LCC)           | QP27C256-200/YA |
| 5962-8606312QXA | GDIP1-T28 CDIP2-T28 (DIP) | QP27C256-250/XA |
| 5962-8606312QYA | CQCC1-N32 (LCC)           | QP27C256-250/YA |
| 5962-8606312UA  | GDIP3-T28 CDIP4-T28 (DIP) | QP27C256-250/UA |
| 5962-8606312XA  | GDIP1-T28 CDIP2-T28 (DIP) | QP27C256-250/XA |
| 5962-8606312YA  | CQCC1-N32 (LCC)           | QP27C256-250/YA |
| 5962-8606313QXA | GDIP1-T28 CDIP2-T28 (DIP) | QP27C256-300/XA |
| 5962-8606313QYA | CQCC1-N32 (LCC)           | QP27C256-300/YA |
| 5962-8606313UA  | GDIP3-T28 CDIP4-T28 (DIP) | QP27C256-300/UA |
| 5962-8606313XA  | GDIP1-T28 CDIP2-T28 (DIP) | QP27C256-300/XA |
| 5962-8606313YA  | CQCC1-N32 (LCC)           | QP27C256-300/YA |
| 5962-8606314QXA | GDIP1-T28 CDIP2-T28 (DIP) | QP27C256-170/XA |
| 5962-8606314QYA | CQCC1-N32 (LCC)           | QP27C256-170/YA |
| 5962-8606314UA  | GDIP3-T28 CDIP4-T28 (DIP) | QP27C256-170/UA |
| 5962-8606314XA  | GDIP1-T28 CDIP2-T28 (DIP) | QP27C256-170/XA |
| 5962-8606314YA  | CQCC1-N32 (LCC)           | QP27C256-170/YA |
| 5962-8606315QXA | GDIP1-T28 CDIP2-T28 (DIP) | QP27C256-150/XA |
| 5962-8606315QYA | CQCC1-N32 (LCC)           | QP27C256-150/YA |
| 5962-8606315UA  | GDIP3-T28 CDIP4-T28 (DIP) | QP27C256-150/UA |
| 5962-8606315XA  | GDIP1-T28 CDIP2-T28 (DIP) | QP27C256-150/XA |
| 5962-8606315YA  | CQCC1-N32 (LCC)           | QP27C256-150/YA |
| 5962-8606316QXA | GDIP1-T28 CDIP2-T28 (DIP) | QP27C256-120/XA |
| 5962-8606316QYA | CQCC1-N32 (LCC)           | QP27C256-120/YA |
| 5962-8606316UA  | GDIP3-T28 CDIP4-T28 (DIP) | QP27C256-120/UA |
| 5962-8606316XA  | GDIP1-T28 CDIP2-T28 (DIP) | QP27C256-120/XA |
| 5962-8606316YA  | CQCC1-N32 (LCC)           | QP27C256-120/YA |
| 5962-8606317QXA | GDIP1-T28 CDIP2-T28 (DIP) | QP27C256-90/XA  |
| 5962-8606317QYA | CQCC1-N32 (LCC)           | QP27C256-90/YA  |
| 5962-8606317UA  | GDIP3-T28 CDIP4-T28 (DIP) | QP27C256-90/UA  |
| 5962-8606317XA  | GDIP1-T28 CDIP2-T28 (DIP) | QP27C256-90/XA  |
| 5962-8606317YA  | CQCC1-N32 (LCC)           | QP27C256-90/YA  |
| 5962-8606318QXA | GDIP1-T28 CDIP2-T28 (DIP) | QP27C256-70/XA  |
| 5962-8606318QYA | CQCC1-N32 (LCC)           | QP27C256-70/YA  |
| 5962-8606318UA  | GDIP3-T28 CDIP4-T28 (DIP) | QP27C256-70/UA  |
| 5962-8606318XA  | GDIP1-T28 CDIP2-T28 (DIP) | QP27C256-70/XA  |
| 5962-8606318YA  | CQCC1-N32 (LCC)           | QP27C256-70/YA  |
| 5962-8606319QXA | GDIP1-T28 CDIP2-T28 (DIP) | QP27C256-55/XA  |
| 5962-8606319QYA | CQCC1-N32 (LCC)           | QP27C256-55/YA  |
| 5962-8606319UA  | GDIP3-T28 CDIP4-T28 (DIP) | QP27C256-55/UA  |
| 5962-8606319XA  | GDIP1-T28 CDIP2-T28 (DIP) | QP27C256-55/XA  |
| 5962-8606319YA  | CQCC1-N32 (LCC)           | QP27C256-55/YA  |
| 5962-8606320QUA | GDIP3-T28 CDIP4-T28 (DIP) | QP27C256-45/UA  |
| 5962-8606320QXA | GDIP1-T28 CDIP2-T28 (DIP) | QP27C256-45/XA  |
| 5962-8606320QYA | CQCC1-N32 (LCC)           | QP27C256-45/YA  |
| 5962-8606321QUA | GDIP3-T28 CDIP4-T28 (DIP) | QP27C256-35/UA  |

| Part Number     | Package (Mil-Std-1835)    | Generic        |
|-----------------|---------------------------|----------------|
| 5962-8606321QXA | GDIP1-T28 CDIP2-T28 (DIP) | QP27C256-35/XA |
| 5962-8606321QYA | CQCC1-N32 (LCC)           | QP27C256-35/YA |

QP Semiconductor supports Source Control Drawing (SCD), and custom package development for this product family.

#### Notes:

Package outline information and specifications are defined by Mil-Std-1835 package dimension requirements.

“-MIL” products manufactured by QP Semiconductor are compliant to the assembly, burn-in, test and quality conformance requirements of Test Methods 5004 & 5005 of Mil-Std-883 for Class B devices. This datasheet defines the electrical test requirements for the device(s).

The listed drawings, Mil-PRF-38535, Mil-Std-883 and Mil-Std-1835 are available online at <http://www.dscc.dla.mil/>

Additional information is available at our website <http://www.qpsemi.com>